

Silicon ESD Protector Overvoltage Protection Device

PRODUCT: SESD0402X1UN-0020-090

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Specification Status: RELEASED

BENEFITS

308 Constitution Drive

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- Industry-leading lowest capacitance; provides lowest insertion loss for high speed data signals
- Small size ESD protection diodes for high speed data signals (0402 size devices)
- Helps protect electronic circuits against damage from Electrostatic Discharge (ESD), surge and cable discharge events
- Assists equipment to pass IEC61000-4-2, level 4 testing

FEATURES

- Low capacitance: 0.20 pF (200fF) (typ)
- Low leakage current : 25nA @ 5V (typ)
- Low clamping voltage: +9.20 / -0.80V (typ)
 @ (tp=8x20µs, lpp=2A)
- ESD maximum rating per IEC61000-4-2 standard:
 - 20kV contact discharge
 - o 20kV air discharge
- Surge: 2A (max) @ (tp=8x20µs) per IEC61000-4-5
- Small size and low profile: XDFN packages

APPLICATIONS

- Consumer, mobile and portable electronics
- Tablet PC and external storage with high speed interfaces
- Ultra-high speed data lines
- USB 3.0/2.0, HDMI 1.3/1.4, DisplayPort, Thunderbolt (Light Peak), V-by-One HS, and LVDS interfaces
- Applications requiring high ESD performance in small packages

MATERIALS INFORMATION



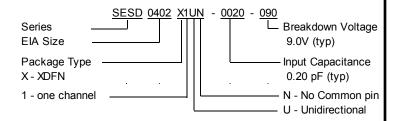
ELV Compliant Halogen Free * Lead Free



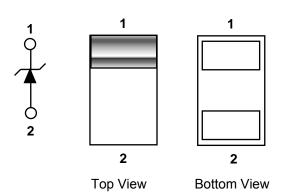
* Halogen Free refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm SESD devices meet MSL-1 Requirements DFN case epoxy meets UL 94 V-0



PART NUMBERING



SCHEMATIC AND PIN CONFIGURATION





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DEVICE MAXIMUM RATING

ESD Withstand ⁽¹⁾ (IEC 61000-4-2, level 4)		Temperature		Peak Current (tp=8x20µs)
Contact (kV)	Air (kV)	Operating (°C)	Storage (°C)	lpp (A)
20	20	-55 to +125	-55 to +150	2.0

⁽¹⁾ 20kV @ 1 pulse; 10kV @ 100 pulses; 8kV @ 1,000 pulses (under IEC6100-4-2)

• Device maximum rating @ T = 25°C, unless otherwise specified

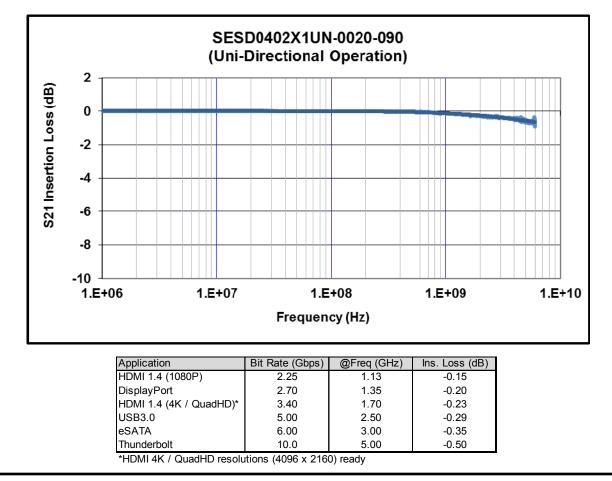
 Caution: Stress exceeding Device Maximum Ratings may damage the device Prolonged exposure to stresses above the recommended operating conditions may affect device reliability

DEVICE ELECTRICAL CHARACTERISTICS

Input Capacitance @ V _R = 0V, f = 3GHz, I/O to GND (pF)		Breakdown Voltage V _{BR} @ I _T =1mA (V)	Reverse Working Voltage (V)		Reverse Leakage Current IL @ V _{RWM} =5.0V (nA)		Clamping Voltage V _{CL} @ lpp=2.0A (V)
Тур	Maximum	Тур	Min	Max	Тур	Max	Тур
0.20	0.22	+9.00 / -0.80	0	+8.00	25.0	50.0	+9.20/-0.80

All device electrical characteristics @ T = 25°C, unless otherwise specified

FIGURE 1. INSERTION LOSS DIAGRAM



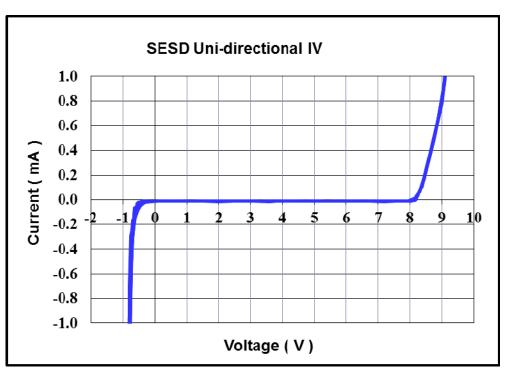


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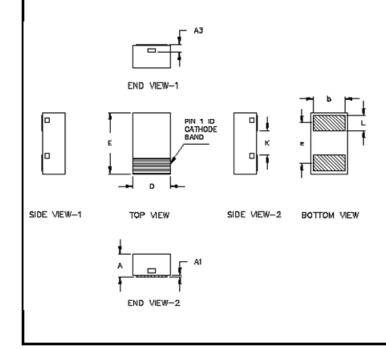
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FIGURE 2. DEVICE IV CURVE



DEVICE DIMENSIONS



	SESD0402 XDFN					
	Miln	neters (r	nm)	Inches (in)		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.33	0.38	0.43	0.013	0.015	0.017
A1	0	-	0.05	0	-	0.002
A3	0.13 ref.			0.005 ref.		
D	0.55	0.60	0.65	0.022	0.024	0.026
E	0.95	1.00	1.05	0.037	0.039	0.041
K	0.35	0.40	0.45	0.014	0.016	0.018
b	0.45	0.50	0.55	0.018	0.020	0.022
L	0.20	0.25	0.30	0.008	0.010	0.012
е	0.65 BSC			0	.026 BS	С

BSC – Basic Spacing between Centers

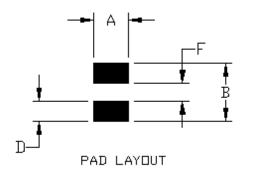


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RECOMMENDED LANDING PATTERN:

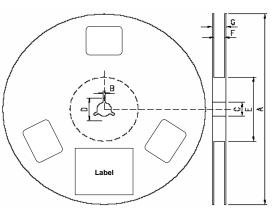


SESD Landing Pad Layout					
0402 Package					
Symbol Milimeters Inches (mm) (in)					
Α	0.60	0.024			
В	1.00	0.039			
D	0.35	0.014			
F	0.30	0.012			

PACKAGING

Packaging	Tape & Reel	Standard Box	
SESD0402X1UN-0020-090	10,000	50,000	

REEL DIMENSIONS



Dimensions	Α	В	С	D	E	F	G
(mm)	180.0 ± 1.5	2.3. 0 ± 0.2	13.0 + 0.5 / -0.2	17.3 ± 0.2	60.5 ± 1.5	8.4 +1.5/-0.0	14.4 (max)
			-				



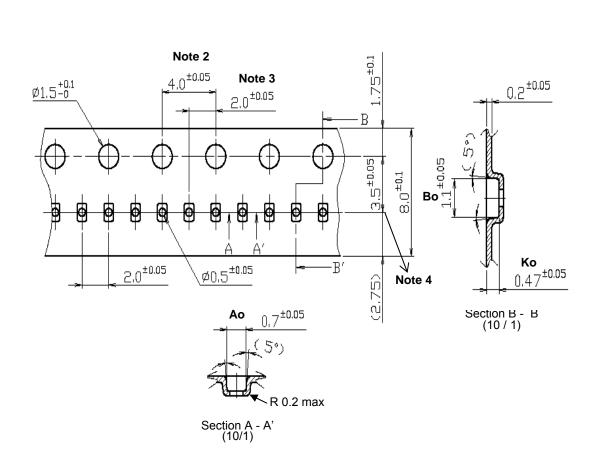
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CARRIER TAPE DIMENSIONS



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Ao	0.07 ± 0.05
Во	1.1 ± 0.05
Ko	0.47 ± 0.05

Note 1. All dimensions in mm

Note 2. Cumulative tolerance is 200 ± 0.3 / 50MM pitch

- Note 3. Center point of hole tolerance is 2.0 ± 0.5
- Note 4. Center point of hole tolerance is 3.5 ± 0.5



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Single Channel

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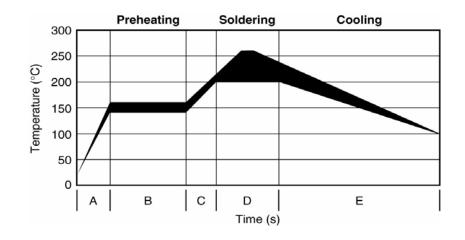
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SOLDER REFLOW RECOMMENDATION

А	TemperatureFrom ambient toramp up 1Preheating temperature		30s to 60s
В	Preheating	140°C - 160°C	60s to 120s
С	Temperature ramp up 2	From Preheating to Main heating temperature	20s to 40s
D	Main heating	at 200°C at 220°C at 240°C at 260°C	60s ~ 70s 50s ~ 60s 30s ~ 40s 5s ~ 10s
Е	Cooling	From main heating temperature to 100°C	4°C/s (max)

FIGURE 3. REFLOW PROFILE



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